

Excellent Integrated System Limited

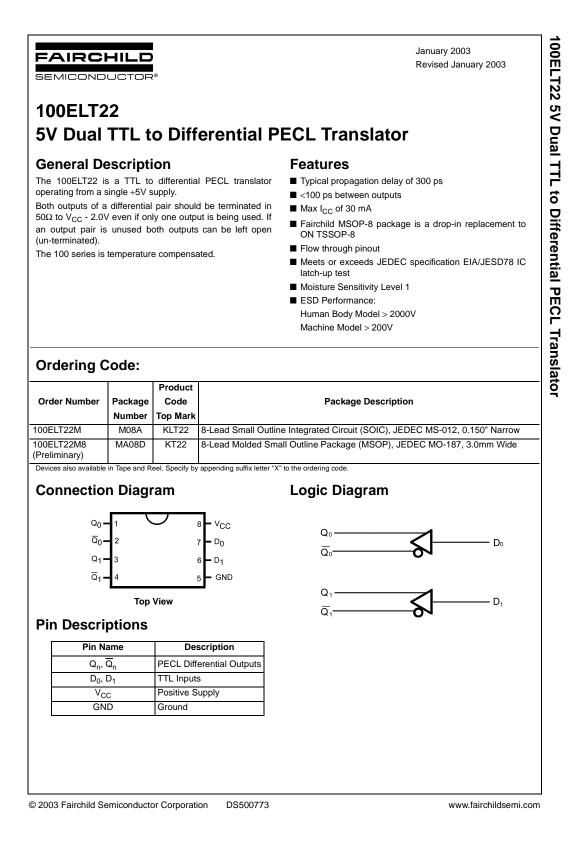
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Fairchild Semiconductor 100ELT22M

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Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of 100ELT22M - TRANSLATOR TTL-DIFF PECL 8SOIC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

100ELT22

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	0.0V to +7.0V
Input Voltage (V _I) $V_I \le V_{CC}$	0.0V to + 7.0V
DC Output Current (I _{OUT})	
Continuous	50 mA
Surge	100 mA
Storage Temperature (T _{STG})	$-65^{\circ}C$ to $+$ 150°C

Recommended Operating Conditions

Power Supply Operating	$V_{CC} = 4.2V$ to 5.5V
TTL Input Voltage	0.0V to V_{CC}
Free Air Operating Temperature (T_A)	$-40^{\circ}C$ to $+85^{\circ}C$

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

PECL DC Electrical Characteristics $V_{CC} = 5.0V$; GND = 0.0V (Note 2)

Symbol	Parameter	-40°C			25°C			85°C			Units
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
I _{CC}	Power Supply Current			30			30			30	mA
V _{OH}	Output HIGH Voltage (Note 3)	3915	3995	4120	3975	4045	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 3)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV

Note 2: Output parameters vary 1 to 1 with V_{CC}. V_{CC} can vary +0.5V/–0.8V.

Note 3: Outputs are terminated through a 50Ω Resistor to V_{CC} – 2.0V.

Note: Devices are designed to meet the DC specifications after thermal equilibrium has been established. Circuit is tested with air flow greater than 500LFPM maintained.

TTL DC Electrical Characteristics $V_{CC} = 5.0V$; GND = 0.0V (Note 4); $T_A = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Min	Тур	Max	Units	Condition
IIH	Input HIGH Current			20		V _{IN} = 2.7V
				100	μA	$V_{IN} = V_{CC}$
IIL	Input LOW Current			-200	μΑ	V _{IN} = 0.5V
V _{IK}	Clamp Diode Voltage			-1.2	V	I _{IN} = -18 mA
VIH	Input HIGH Voltage	2.0			V	
VIL	Input LOW Voltage			0.8	V	

Note 4: V_{CC} can vary +0.5V/-0.8V.

AC Electrical Characteristics $V_{CC} = 5.0V$; GND = 0.0V (Note 5)

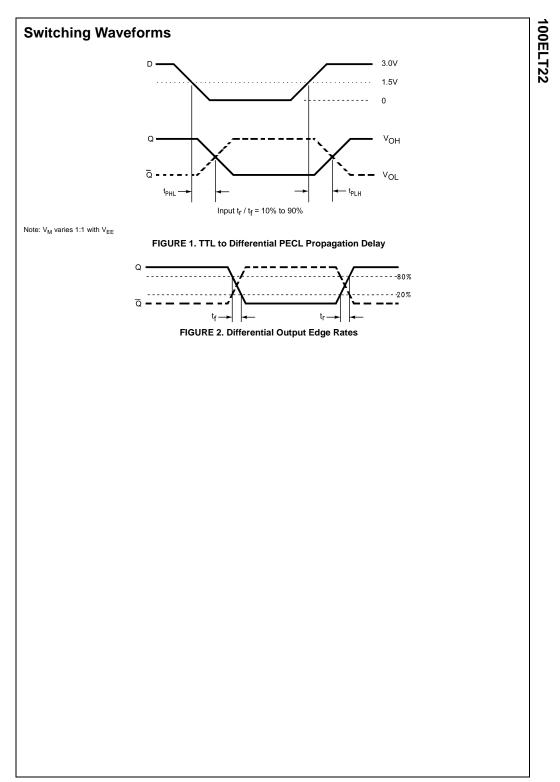
Symbol	Parameter	−40°C		25°C			85°C			Units	Figure	
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Onits	Number
f _{MAX}	Maximum Input Frequency		TBD			TBD			TBD		MHz	
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps	
t _{PLH} , t _{PHL}	Propagation Delay to Output (Note 6)	100		600	100		600	100		600	ps	Figure 1
t _r , t _f	Output Rise Time/Fall Times (20% to 80%)	200		500	200		500	200		500	ns	Figure 2
t _{skpp}	Part to Part Skew			500			500			500	ps	
t _{skew}	Within Device Skew (Note 7)			100			100			100	ps	

Note 5: V_{CC} can vary +0.5V/-0.8V.

Note 6: Specifications for standard TTL input signal (see Figure 1).

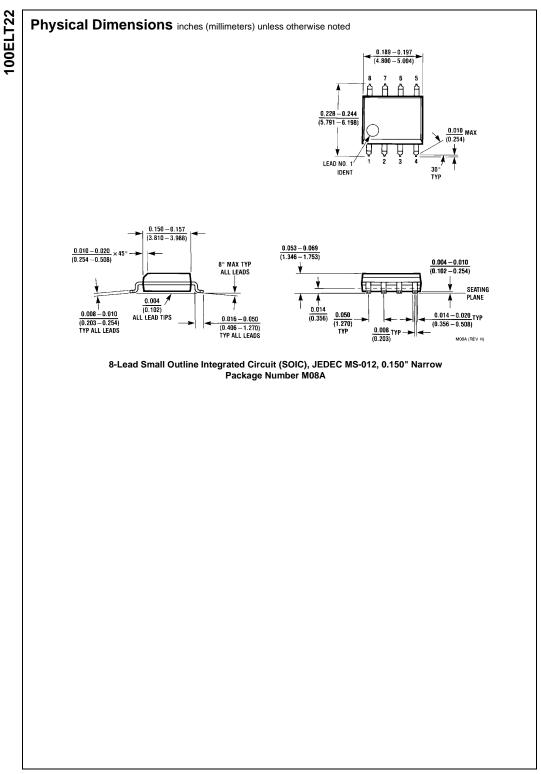
Note 7: Within-device skew is defined as identical transitions on similar paths through a device.





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